

SPECIFICATION

Device Name : IGBT-IPM

Type Name : 6MBP75NA060-01

Spec. No. : MS6M0276

Fuji Electric Co.,Ltd.
Matsumoto Factory

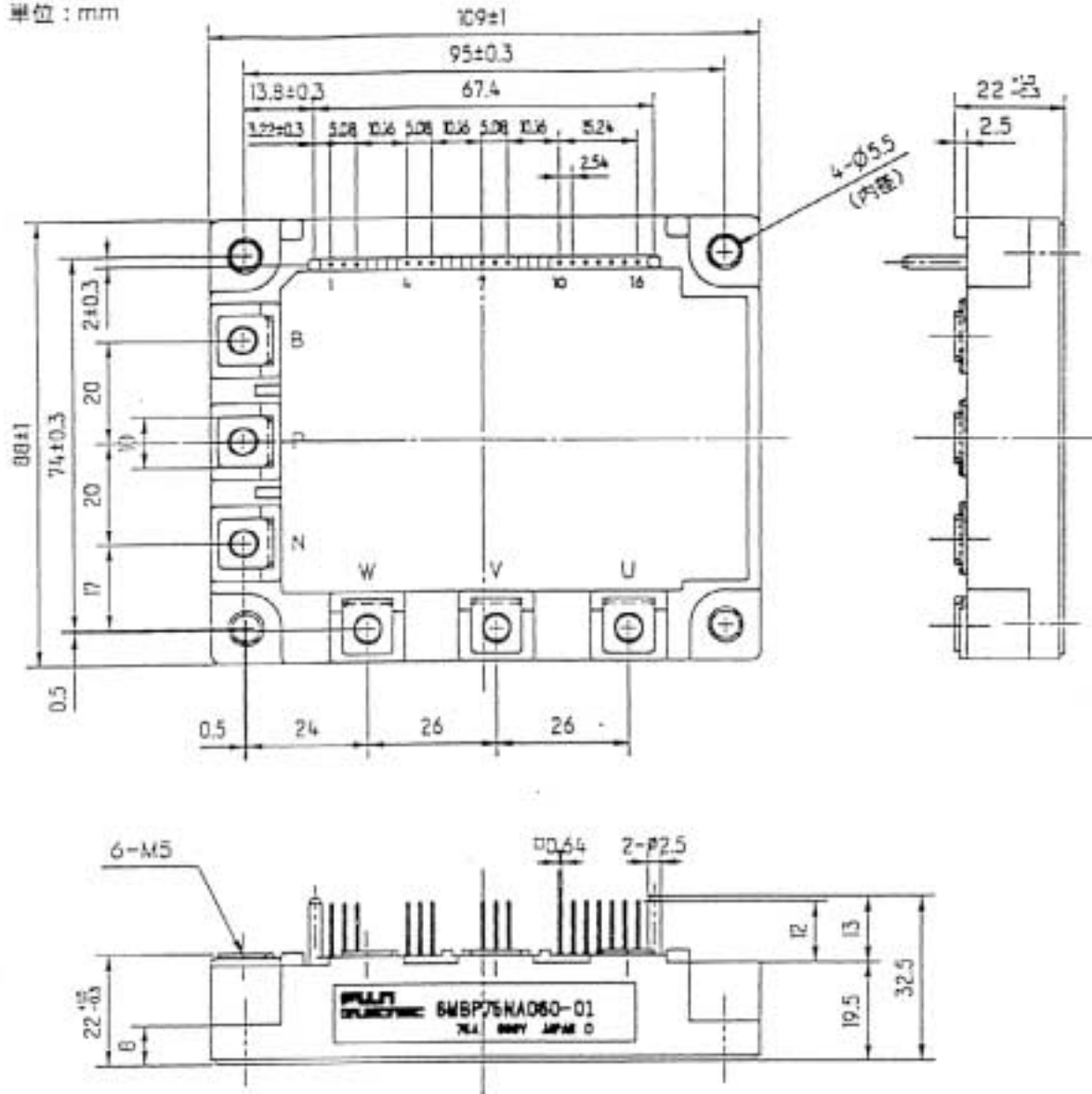
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1. Outline Drawing

外形圖

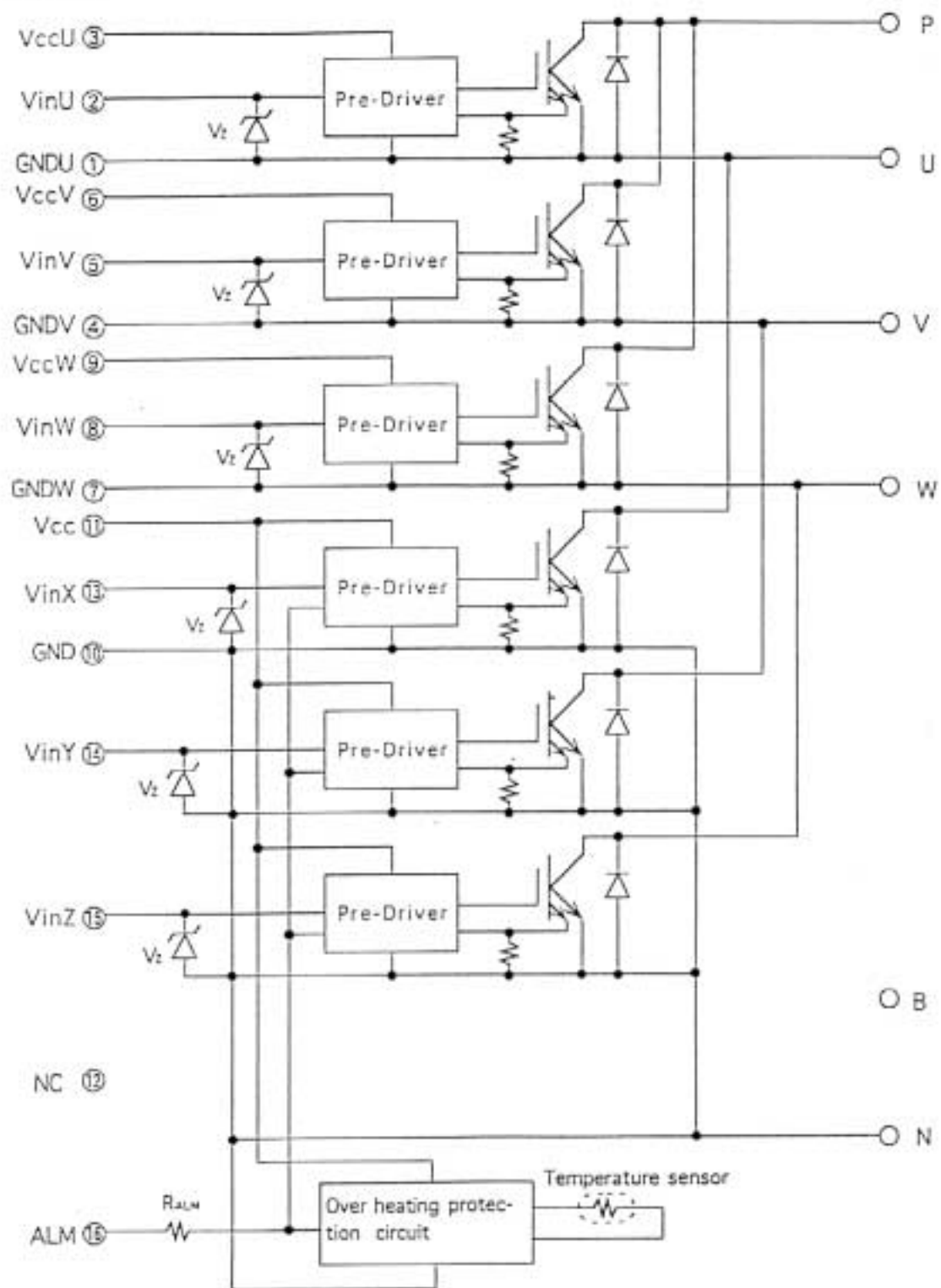
Unit : mm

單位 : mm



2 Block Diagram

ブロック図



Pre-Drivers include following functions

- ① Short Circuit Protection Circuit
- ② Amplifier for Driver
- ③ Under Voltage Lockout Circuit
- ④ Over current Protection Circuit

3. Absolute Maximum Ratings (at $T_c=25^{\circ}\text{C}$ unless otherwise specified)

Items		Symbols	Ratings		Units	
			Min.	Max.		
DC Bus Voltage		V_{bc}	0	450	V	
DC Bus Voltage (surge)		$V_{bc(SURGE)}$	0	500	V	
DC Bus Voltage (short operating)		V_{sc}	200	400	V	
Collector-Emitter Voltage		V_{CES}	0	600	V	
I N V	Collector Current	DC	I_c	—	75	A
		1mS	I_{cp}	—	150	A
		Duty=61.7%	$-I_c$	—	75	A
Collector Power Dissipation One Transistor		P_c	—	320	W	
Junction Temperature		T_j	—	150	$^{\circ}\text{C}$	
Input Voltage of Power Supply for Pre-Driver		V_{cc} ※1	0	20	V	
Input Signal Voltage		V_{in} ※2	0	V_z	V	
Input Signal Current		I_{in}	—	1	mA	
Alarm Signal Voltage		V_{ALM} ※3	0	V_{cc}	V	
Alarm Signal Current		I_{ALM} ※4	—	15	mA	
Storage Temperature		T_{stg}	-40	125	$^{\circ}\text{C}$	
Operating Case Temperature (Fig.1)		T_{OP}	-20	100	$^{\circ}\text{C}$	
Isolation Voltage (Case-Terminal)		V_{iso} ※5	—	AC2.5	kV	

- Note ※1 V_{cc} shall be applied to the input Voltage between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.
 ※2 V_{in} shall be applied to the input Voltage between terminal No. 2 and 1, 5 and 4, 8 and 7, 12 13 14 15 and 10.
 ※3 V_{ALM} shall be applied to the Voltage between terminal No. 16 and 10.
 ※4 I_{ALM} shall be applied to the input current to terminal No. 16.
 ※5 50Hz/60Hz sine wave 1 minute.

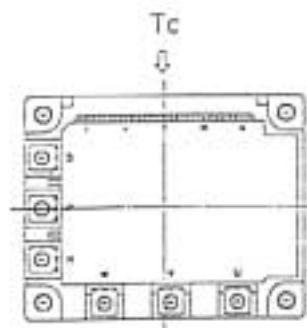


Fig.1 Measurement of case temperature

4. Electrical Characteristics

4.1 Electrical Characteristics of Power Circuit (at $T_c=T_j=25^\circ\text{C}, V_{cc}=15\text{V}$)

Items		Symbols	Conditions	Min.	Typ.	Max.	Units
I N V	Collector Current at off Signal Input	I_{ces}	$V_{CE}=600\text{V}$	—	—	1.0	mA
	Collector-Emitter Saturation Voltage	$V_{ce(sat)}$	$I_c=75\text{A}$	—	—	2.9	V
	Forward Voltage of FWD	V_f	$-I_c=75\text{A}$	—	—	3.0	V

4.2 Electrical Characteristics of Control Circuit (at $T_c=T_j=25^\circ\text{C}, V_{cc}=15\text{V}$)

Items		Symbols	Conditions	Min.	Typ.	Max.	Units
Power Supply Current of P-Line Side Pre-Driver (One Unit)		I_{ccp}	$f_{sw}=15\text{kHz} \times 6$ Duty=50%	—	7	17	mA
Power Supply Current of N-Line Side Three Pre-Drivers and Protection Circuits		I_{ccn}	$f_{sw}=15\text{kHz}$ Duty=50%	—	21	51	mA
Input signal Threshold Voltage		$V_{in(on)}$	ON	1.00	1.35	1.70	V
		$V_{in(off)}$	OFF	1.25	1.60	1.95	
Zener Voltage		V_z		6.9	—	7.7	V
Over Heating Protection(OH) Level		T_{OH}	$V_{DC}=0\text{V}, I_c=0\text{A}$ Case Temperature	100	—	125	$^\circ\text{C}$
OH Hysteresis		T_H		—	20	—	$^\circ\text{C}$
Over Current Protection(OC) Level	INV	I_{oc}	$T_j=125^\circ\text{C}$ Collector Current	98	—	—	A
OC Delay Time (Fig.2)		t_{boc}	$T_j=25^\circ\text{C}$	—	8	—	μS
Under Voltage Protection(UV) Level		V_{uvr}		11.0	12.0	12.5	V
UV Hysteresis		V_H		0.2	—	—	V
Alarm Signal Hold Time		t_{ALM}		0.8	2	—	mS
Delay Time of Short Circuit Protection (Fig.3)		t_{sc}		12	—	—	μS
Limiting Resistor for Alarm		R_{ALM}		1425	1500	1575	Ω

$\times 6$ Switching frequency of IPM

4.3 Dynamic Characteristics (at $T_c=T_j=125^\circ\text{C}, V_{cc}=15\text{V}$)

Items		Symbols	Conditions	Min.	Typ.	Max.	Units
Switching Time Fig.4		t_{on}	$I_c=75\text{A}$	0.3	—	—	μS
		t_{off}	$V_{bc}=300\text{V}$	—	—	3.6	μS
Switching Time (FWD)		t_{rr}	$I_F=75\text{A}, V_{DC}=300\text{V}$	—	—	400	nS

5. Thermal Characteristics (Tc=25℃)

Items		Symbols	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	INV IGBT	Rth(j-c)	—	—	0.39	℃/W
	FWD	Rth(j-c)	—	—	0.90	℃/W
Case to Fin Thermal Resistance with Compound		Rth(c-f)	—	0.05	—	℃/W

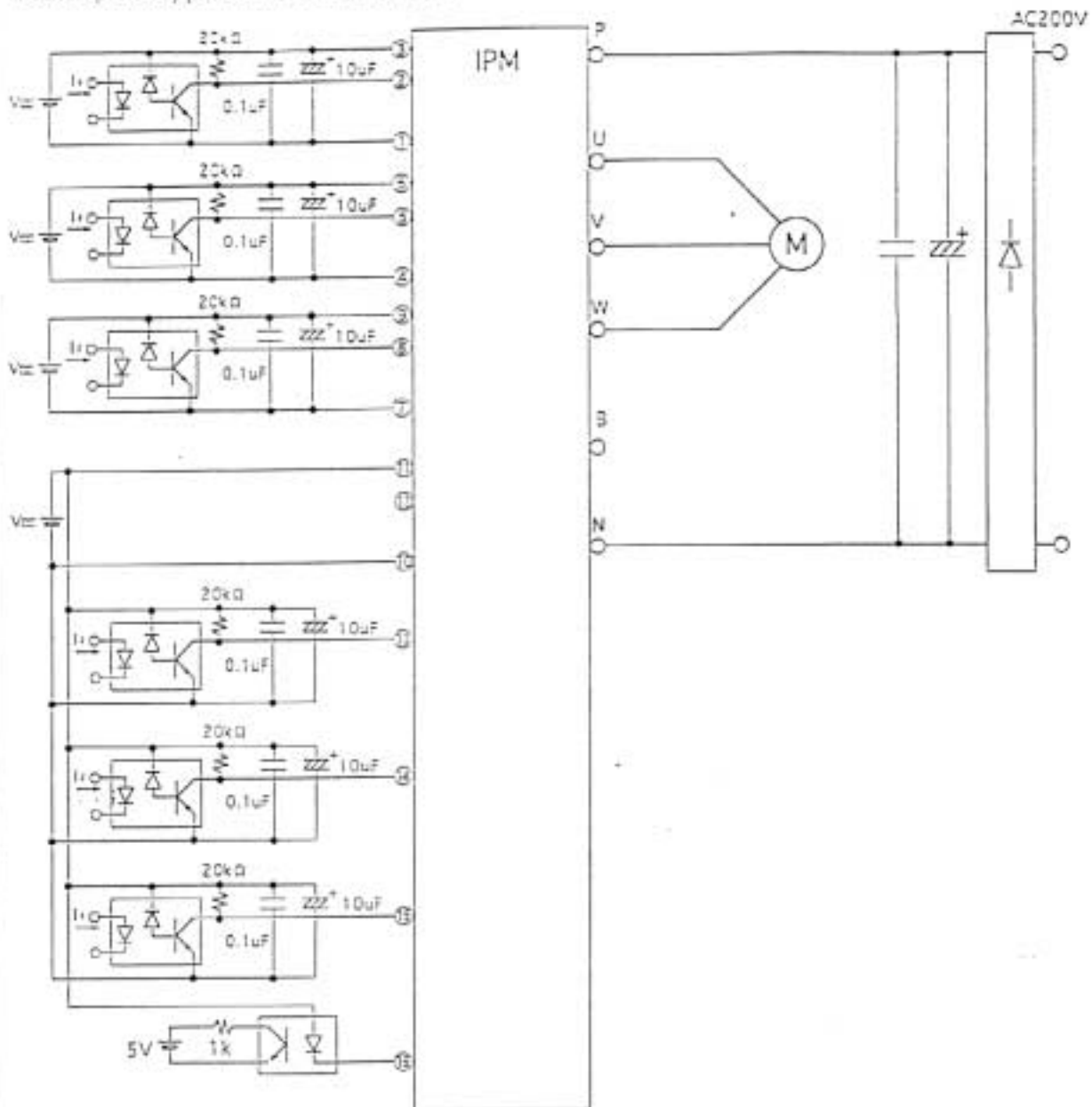
6. Mechanical Characteristics

Items		Min.	Typ.	Max.	Units
Screw Torque	Mounting (M5)	—	—	3.5	N·m
	Terminal (M5)	—	—	3.5	N·m
Weight		—	550	—	g

7. Recommendable Value

Items		Symbols	Conditions	Min.	Typ.	Max.	Units
DC Bus Voltage		Vbc		200	—	400	V
Operating Power Supply Voltage Range of Pre-Driver		Vcc		13.5	15	16.5	V
Switching frequency of IPM		fsw		1	—	20	kHz
Screw Torque	Mounting (M5)	—		2.5	—	3.5	N·m
	Terminal (M5)	—		2.5	—	3.5	N·m

1.2. Example of applied circuit (応用回路例)



- The wiring between opto-coupler and input terminal of IPM should be shorter as much as possible. The stray-capacitance between primary and secondary side of opto-coupler should not be increased by pattern lay-out.
 ホトカブラとIPMの入力端子間配線は、できるだけ短くしホトカブラの1次・2次間の浮遊容量を増加させないパターンレイアウトとして下さい。
- Capacitor should be installed to VCC-GND terminal of high-speed opto-coupler closely as much as possible.
 高速ホトカブラのVcc-GND間には、コンデンサをできるだけ近接して取り付けて下さい。
- Use high-speed opto-coupler : $t_{PLH}, t_{PHL} \leq 0.8\mu s$, high CMR type. (Example : HCPL-4504)
 高速ホトカブラ : $t_{PLH}, t_{PHL} \leq 0.8\mu s$, 高CMRタイプをご使用下さい。(例 HPCL-4504)
- Low-speed opto-coupler : CTR $\geq 100\%$
 低速ホトカブラ : CTR $\geq 100\%$